

TVS Diode

Transient Voltage Suppressor Diodes

ESD113-B1-02ELS

Bi-directional Ultra Low Capacitance ESD / Transient Protection Diode

ESD113-B1-02ELS

Data Sheet

Revision 1.1, 2013-02-06
Final

Edition 2013-02-06

**Published by
Infineon Technologies AG
81726 Munich, Germany**

**© 2013 Infineon Technologies AG
All Rights Reserved.**

Legal Disclaimer

The information given in this document shall in no event be regarded as a guarantee of conditions or characteristics. With respect to any examples or hints given herein, any typical values stated herein and/or any information regarding the application of the device, Infineon Technologies hereby disclaims any and all warranties and liabilities of any kind, including without limitation, warranties of non-infringement of intellectual property rights of any third party.

Information

For further information on technology, delivery terms and conditions and prices, please contact the nearest Infineon Technologies Office (www.infineon.com).

Warnings

Due to technical requirements, components may contain dangerous substances. For information on the types in question, please contact the nearest Infineon Technologies Office.

Infineon Technologies components may be used in life-support devices or systems only with the express written approval of Infineon Technologies, if a failure of such components can reasonably be expected to cause the failure of that life-support device or system or to affect the safety or effectiveness of that device or system. Life support devices or systems are intended to be implanted in the human body or to support and/or maintain and sustain and/or protect human life. If they fail, it is reasonable to assume that the health of the user or other persons may be endangered.

Revision History: Rev.1.0, 2013-01-25

Page or Item	Subjects (major changes since previous revision)
--------------	--

Revision 1.1, 2013-02-06

5	Table 2-1 updated

Trademarks of Infineon Technologies AG

AURIX™, BlueMoon™, C166™, CanPAK™, CIPOS™, CIPURSE™, COMNEON™, EconoPACK™, CoolMOS™, CoolSET™, CORECONTROL™, CROSSAVE™, DAVE™, EasyPIM™, EconoBRIDGE™, EconoDUAL™, EconoPIM™, EiceDRIVER™, eupec™, FCOS™, HITFET™, HybridPACK™, I²RF™, ISOFACE™, IsoPACK™, MIPAK™, ModSTACK™, my-d™, NovalithIC™, OmniTune™, OptiMOS™, ORIGAT™, PRIMARION™, PrimePACK™, PrimeSTACK™, PRO-SIL™, PROFET™, RASIC™, ReverSave™, SatRIC™, SIEGET™, SINDRION™, SIPMOS™, SMARTi™, SmartLEWIS™, SOLID FLASH™, TEMPFET™, thinQ!™, TRENCHSTOP™, TriCore™, X-GOLD™, X-PMU™, XMM™, XPOSYS™.

Other Trademarks

Advance Design System™ (ADS) of Agilent Technologies, AMBA™, ARM™, MULTI-ICE™, KEIL™, PRIMECELL™, REALVIEW™, THUMB™, µVision™ of ARM Limited, UK. AUTOSAR™ is licensed by AUTOSAR development partnership. Bluetooth™ of Bluetooth SIG Inc. CAT-iq™ of DECT Forum. COLOSSUS™, FirstGPS™ of Trimble Navigation Ltd. EMV™ of EMVCo, LLC (Visa Holdings Inc.). EPCOS™ of Epcos AG. FLEXGO™ of Microsoft Corporation. FlexRay™ is licensed by FlexRay Consortium. HYPERTERMINAL™ of Hilgraeve Incorporated. IEC™ of Commission Electrotechnique Internationale. IrDA™ of Infrared Data Association Corporation. ISO™ of INTERNATIONAL ORGANIZATION FOR STANDARDIZATION. MATLAB™ of MathWorks, Inc. MAXIM™ of Maxim Integrated Products, Inc. MICROTEC™, NUCLEUS™ of Mentor Graphics Corporation. Mifare™ of NXP. MIPI™ of MIPI Alliance, Inc. MIPS™ of MIPS Technologies, Inc., USA. muRata™ of MURATA MANUFACTURING CO., MICROWAVE OFFICE™ (MWO) of Applied Wave Research Inc., OmniVision™ of OmniVision Technologies, Inc. Openwave™ Openwave Systems Inc. RED HAT™ Red Hat, Inc. RFMD™ RF Micro Devices, Inc. SIRIUS™ of Sirius Satellite Radio Inc. SOLARIS™ of Sun Microsystems, Inc. SPANSION™ of Spansion LLC Ltd. Symbian™ of Symbian Software Limited. TAIYO YUDEN™ of Taiyo Yuden Co. TEAKLITE™ of CEVA, Inc. TEKTRONIX™ of Tektronix Inc. TOKO™ of TOKO KABUSHIKI KAISHA TA. UNIX™ of X/Open Company Limited. VERILOG™, PALLADIUM™ of Cadence Design Systems, Inc. VLYNQ™ of Texas Instruments Incorporated. VXWORKS™, WIND RIVER™ of WIND RIVER SYSTEMS, INC. ZETEX™ of Diodes Zetex Limited.

Last Trademarks Update 2010-10-26

1 Bi-directional Ultra Low Capacitance ESD / Transient Protection Diode

1.1 Features

- ESD / transient protection of high speed data lines exceeding
 - IEC61000-4-2 (ESD): ± 20 kV (air / contact)
 - IEC61000-4-4 (EFT): ± 2.5 kV / ± 50 A (5/50 ns)
 - IEC61000-4-5 (surge): ± 3 A (8/20 μ s)
- Maximum working voltage: $V_{RWM} = \pm 3.6$ V
- Ultra low capacitance $C_L = 0.20$ pF (typical) at $f = 1$ GHz
- Very low clamping voltage: $V_{CL} = 14$ V at $I_{TLP} = 16$ A (typical) according to TLP [1]
- Very low dynamic resistance: $R_{DYN} = 0.45$ Ω (typical)
- Pb-free and halogen-free package (RoHS compliant)



1.2 Application Examples

- USB 3.0, Firewire, DVI, HDMI, S-ATA, DisplayPort, Thunderbolt
- Mobile HDMI Link, MDDI, MIPI, SWP / NFC

1.3 Product Description

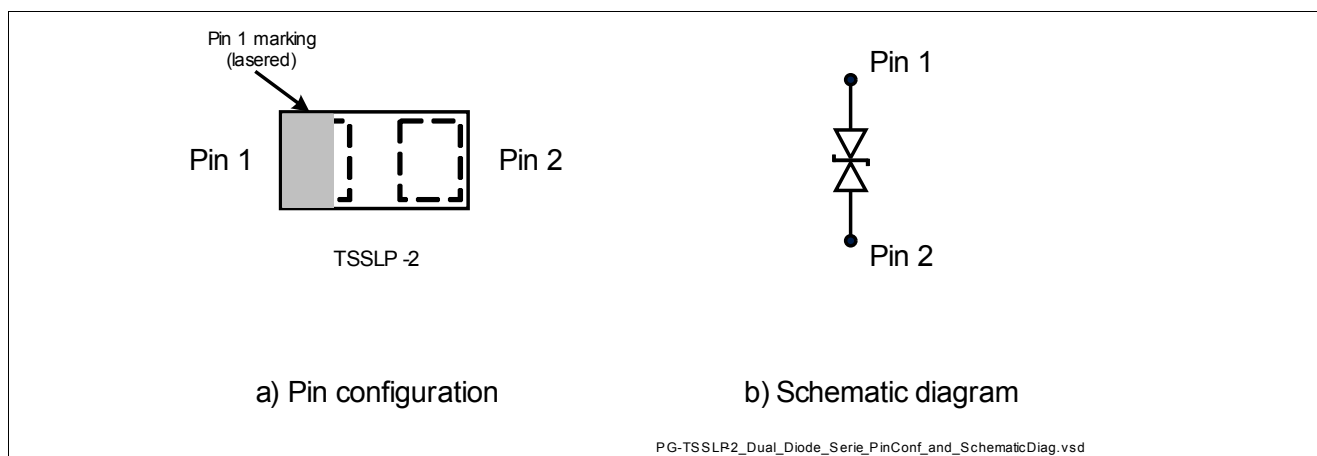


Figure 1-1 Pin Configuration and Schematic Diagram

Table 1-1 Ordering Information

Type	Package	Configuration	Marking code
ESD113-B1-02ELS	PG-TSSLP-2-4	1 line, bi-directional	<u>2</u>

2 Characteristics

Table 2-1 Maximum Rating at $T_A = 25\text{ °C}$, unless otherwise specified

Parameter	Symbol	Values			Unit
		Min.	Typ.	Max.	
ESD (air / contact) discharge ¹⁾	V_{ESD}	-20	–	20	kV
Peak pulse current ($t_p = 8/20\text{ }\mu\text{s}$) ²⁾	I_{PP}	-3	–	3	A
Operating temperature range	T_{OP}	-40	–	125	°C
Storage temperature	T_{stg}	-65	–	150	°C

1) V_{ESD} according to IEC61000-4-2 ($R = 330\text{ }\Omega$, $C = 150\text{ pF}$ discharge network)

2) I_{PP} according to IEC61000-4-5

Attention: Stresses above the max. values listed here may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect device reliability. Maximum ratings are absolute ratings; exceeding only one of these values may cause irreversible damage to the component.

2.1 Electrical Characteristics at $T_A = 25\text{ °C}$, unless otherwise specified

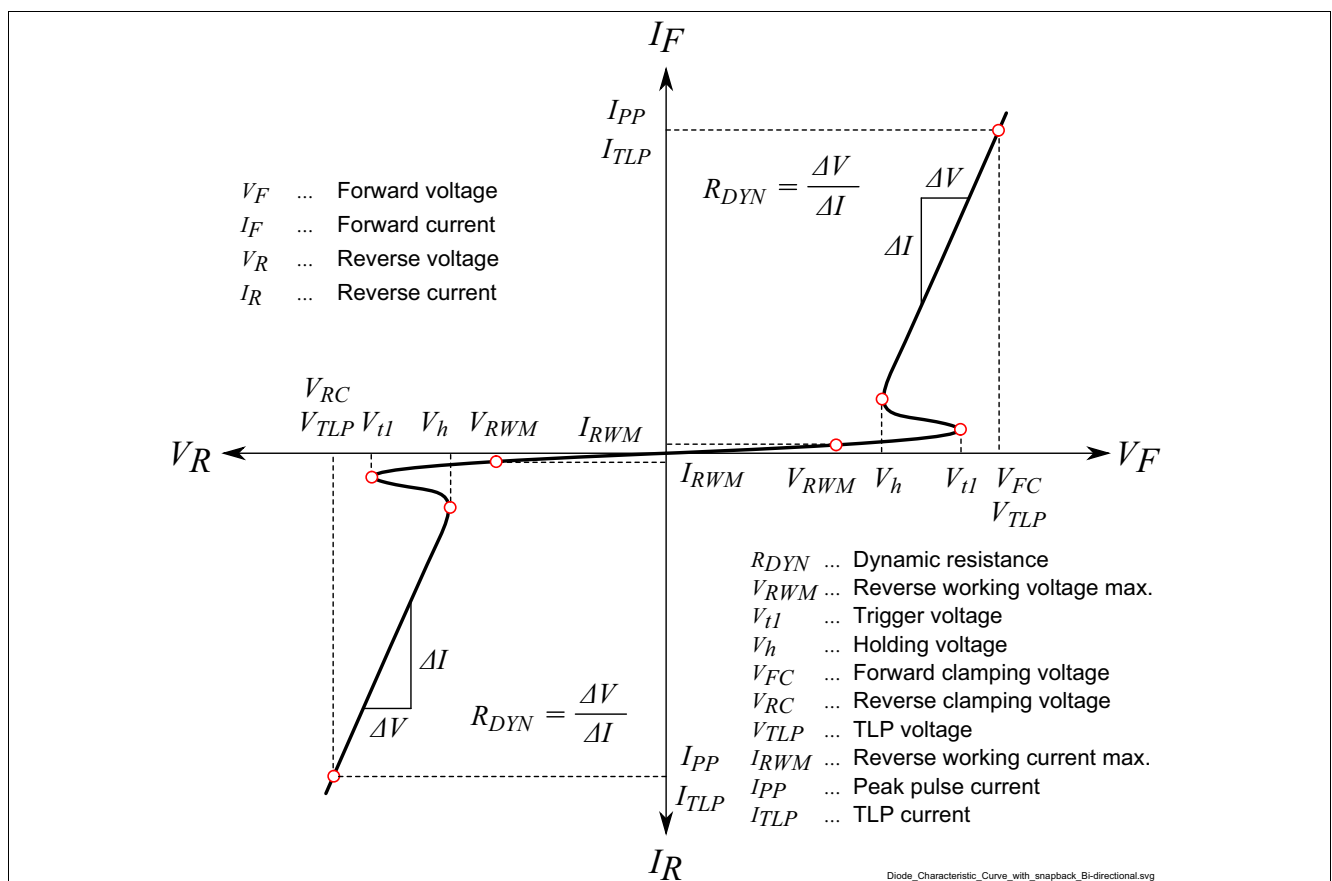


Figure 2-1 Definitions of electrical characteristics

Characteristics

Table 2-2 DC Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Reverse working voltage	V_{RWM}	-3.6	–	3.6	V	
Reverse current	I_R	–	1	50	nA	$V_R = 3.3\text{ V}$

Table 2-3 RF Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Line capacitance	C_L	–	0.22	0.35	pF	$V_R = 0\text{ V}, f = 1\text{ MHz}$
		–	0.20	–		$V_R = 0\text{ V}, f = 1\text{ GHz}$
Series inductance	L_S	–	0.2	–	nH	

Table 2-4 ESD Characteristics at $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

Parameter	Symbol	Values			Unit	Note / Test Condition
		Min.	Typ.	Max.		
Clamping voltage ¹⁾	V _{CL}	—	14	—	V	I _{TLP} = 16 A
		—	20	—		I _{TLP} = 30 A
Clamping voltage ²⁾		—	12	—		V _{ESD} = 8 kV
		—	18	—		V _{ESD} = 15 kV
Clamping voltage ³⁾		—	8	—		I _{PP} = 3 A
Dynamic resistance ¹⁾	R _{DYN}	—	0.45	—	Ω	
Dynamic resistance ³⁾		—	1	—		

1) ANSI/ESD STM5.5.1 - Electrostatic Discharge Sensitive Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50\text{ }\Omega$, $t_p = 100\text{ ns}$, $t_r = 0.6\text{ ns}$ and V_{TLP} averaging window: $t_1 = 30\text{ ns}$ to $t_2 = 60\text{ ns}$, extraction of dynamic resistance using least squares fit of TLP characteristic between $I_{TLP1} = 5\text{ A}$ and $I_{TLP2} = 40\text{ A}$. Please refer to Application Note AN210[1].

2) V_{ESD} according to IEC61000-4-2, V_{CL} at 30 ns ($R = 330\text{ }\Omega$, $C = 150\text{ pF}$ discharge network)

3) I_{PP} according to IEC61000-4-5 ($t_p = 8/20\text{ }\mu\text{s}$)

3 Typical Characteristics

At $T_A = 25\text{ }^{\circ}\text{C}$, unless otherwise specified

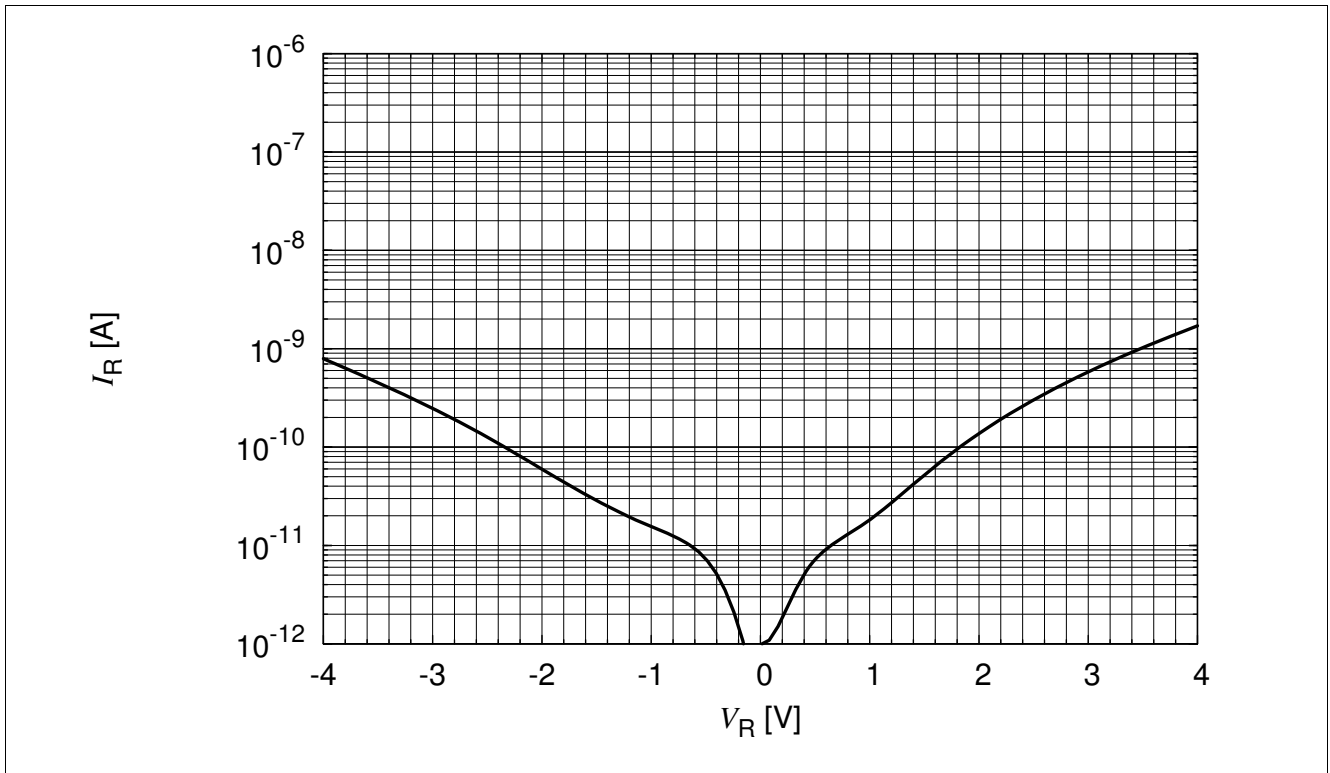


Figure 3-1 Reverse current $I_R = f(V_R)$

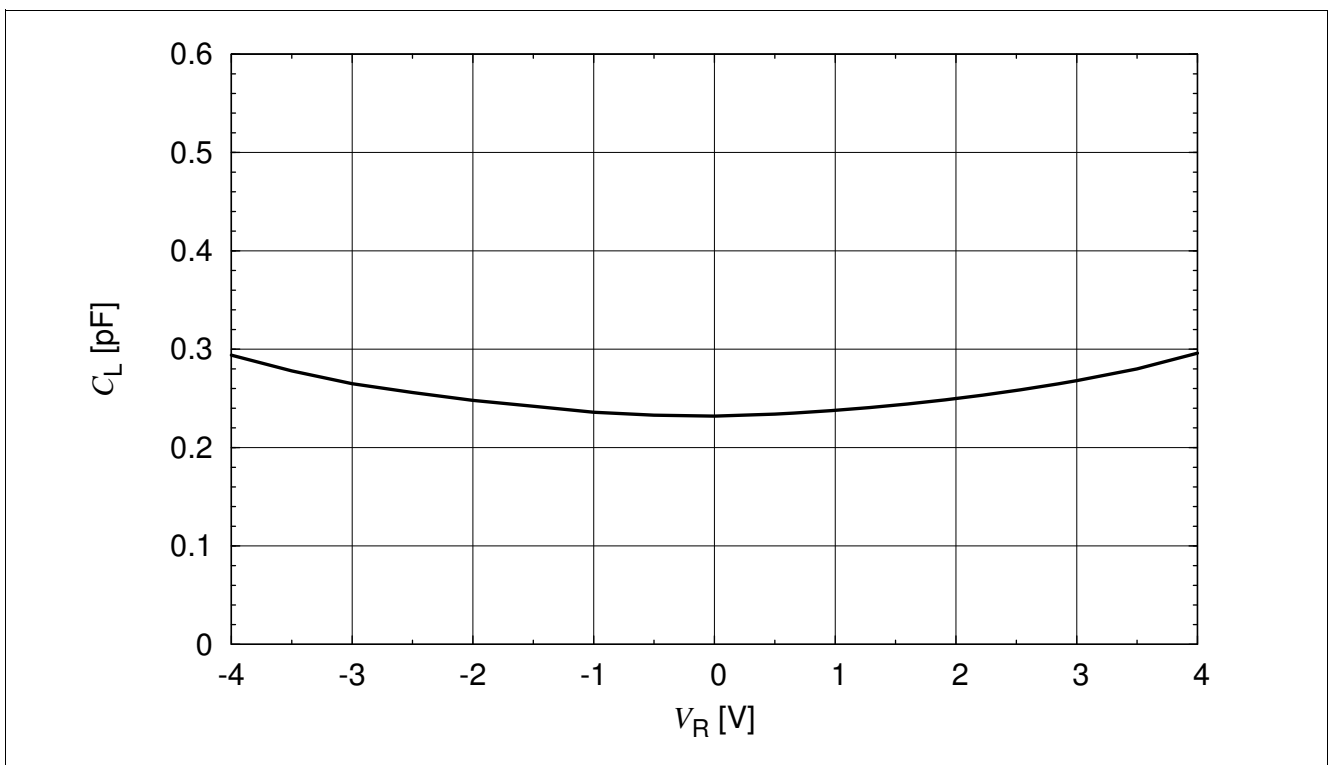


Figure 3-2 Line capacitance $C_L = f(V_R)$, $f = 1\text{ MHz}$

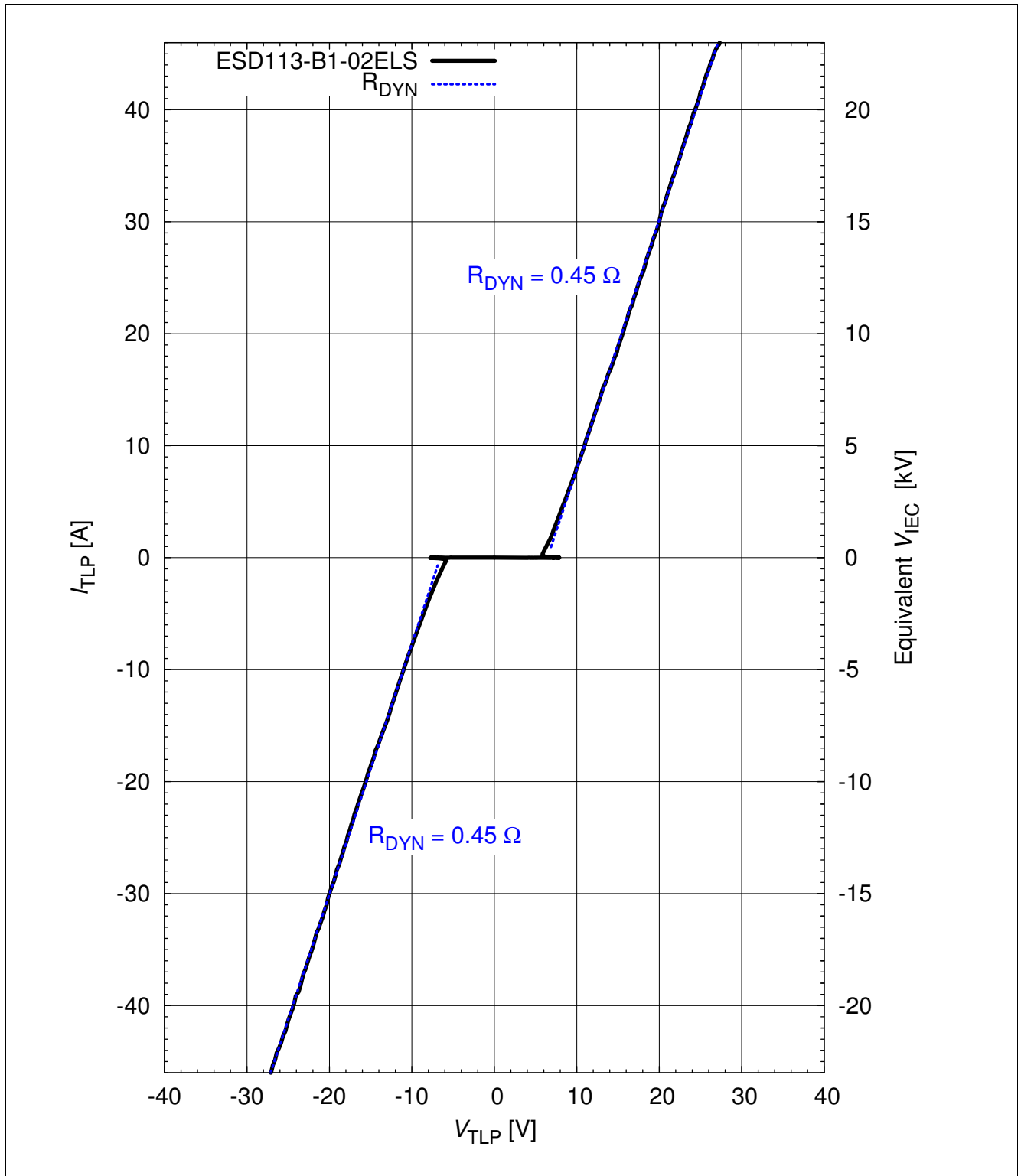


Figure 3-3 Clamping voltage (TLP): $I_{TLP} = f(V_{TLP})$ according ANSI/ESD STM5.5.1- Electrostatic Discharge Sensitivity Testing using Transmission Line Pulse (TLP) Model. TLP conditions: $Z_0 = 50 \Omega$, $t_p = 100$ ns, $t_r = 0.6$ ns, I_{TLP} and V_{TLP} averaging window: $t_1 = 30$ ns to $t_2 = 60$ ns, extraction of dynamic resistance using squares fit to TLP characteristics between $I_{TLP1} = 5$ A and $I_{TLP2} = 40$ A. Please refer to Application Note AN210[1]

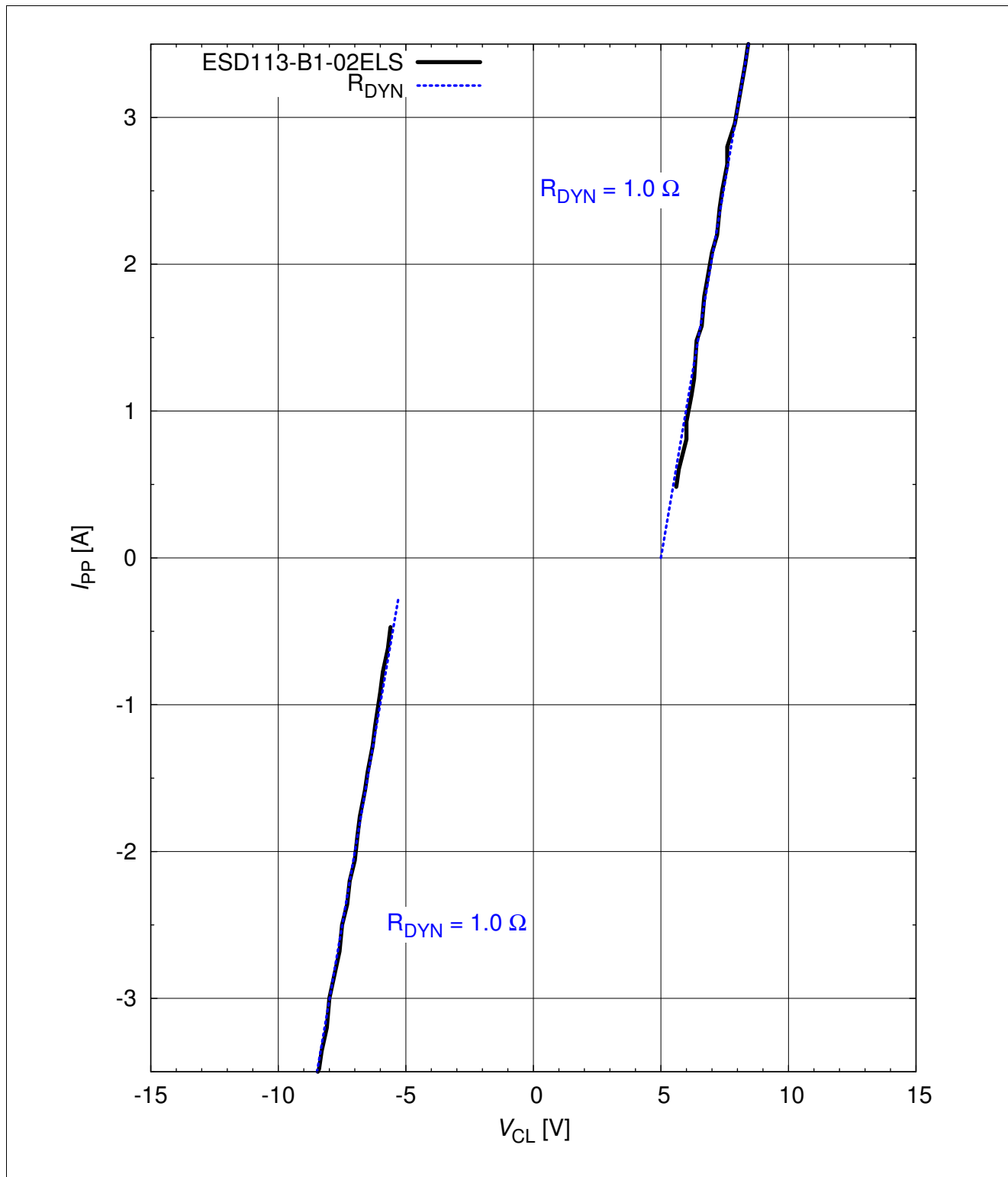


Figure 3-4 Pulse current (IEC61000-4-5) versus clamping voltage: $I_{PP} = f(V_{CL})$

Typical Characteristics

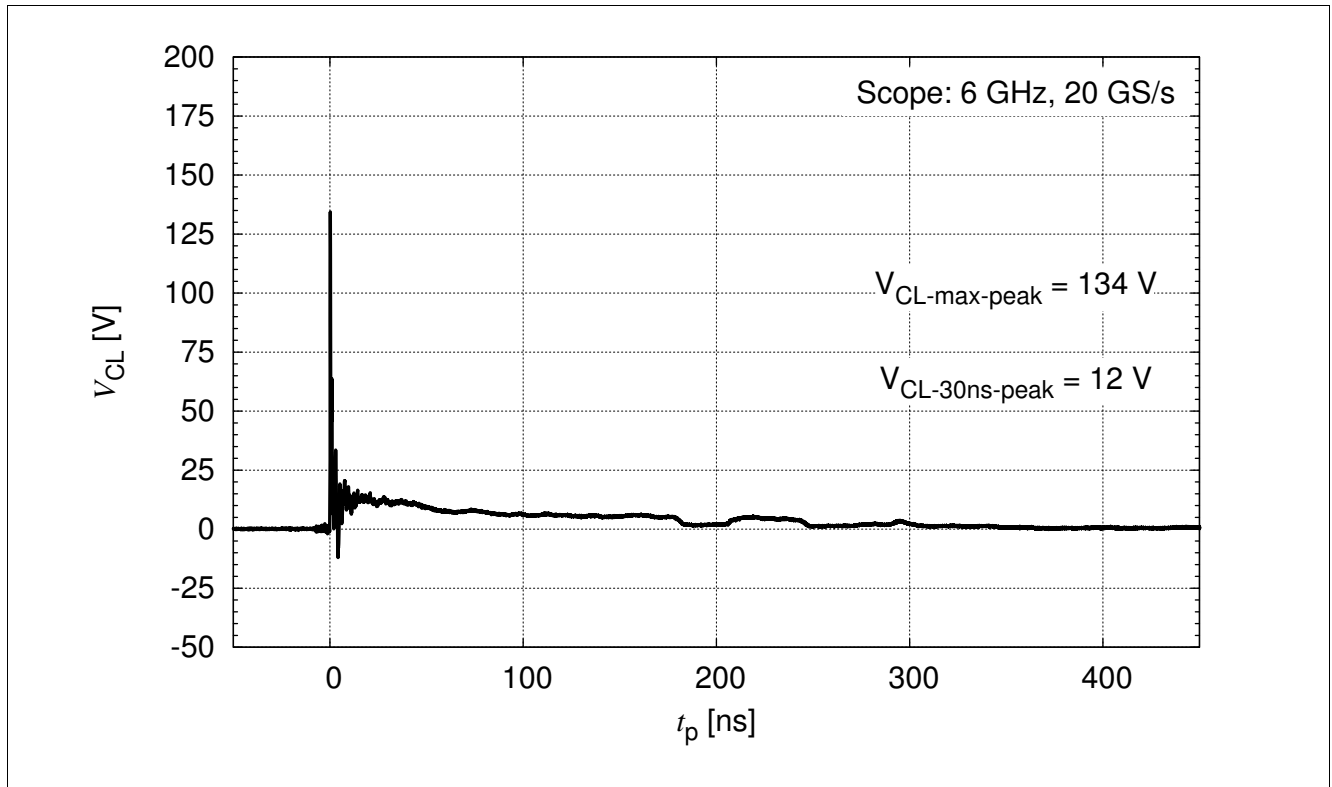


Figure 3-5 Clamping voltage at +8 kV discharge according IEC61000-4-2 ($R = 330 \Omega$, $C = 150 \text{ pF}$)

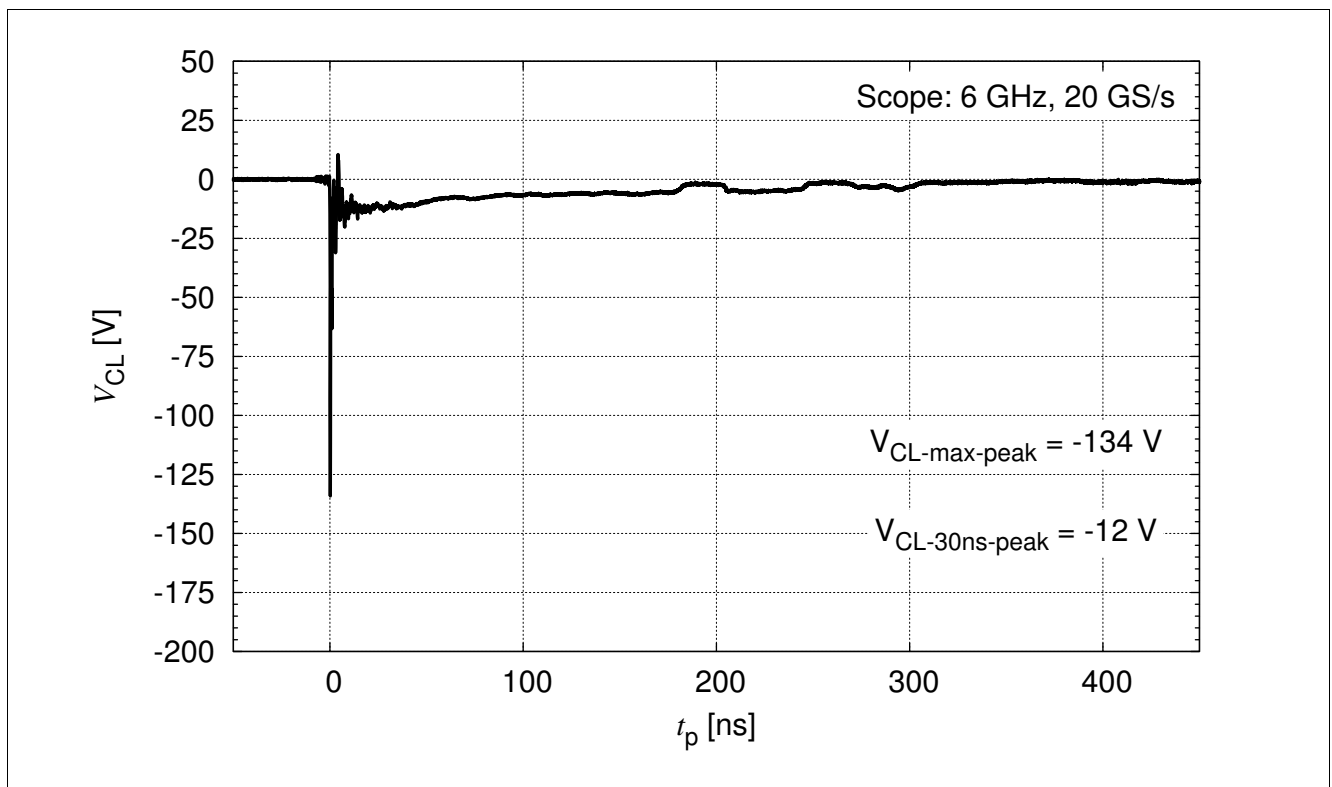


Figure 3-6 Clamping voltage at -8 kV discharge according IEC61000-4-2 ($R = 330 \Omega$, $C = 150 \text{ pF}$)

Typical Characteristics

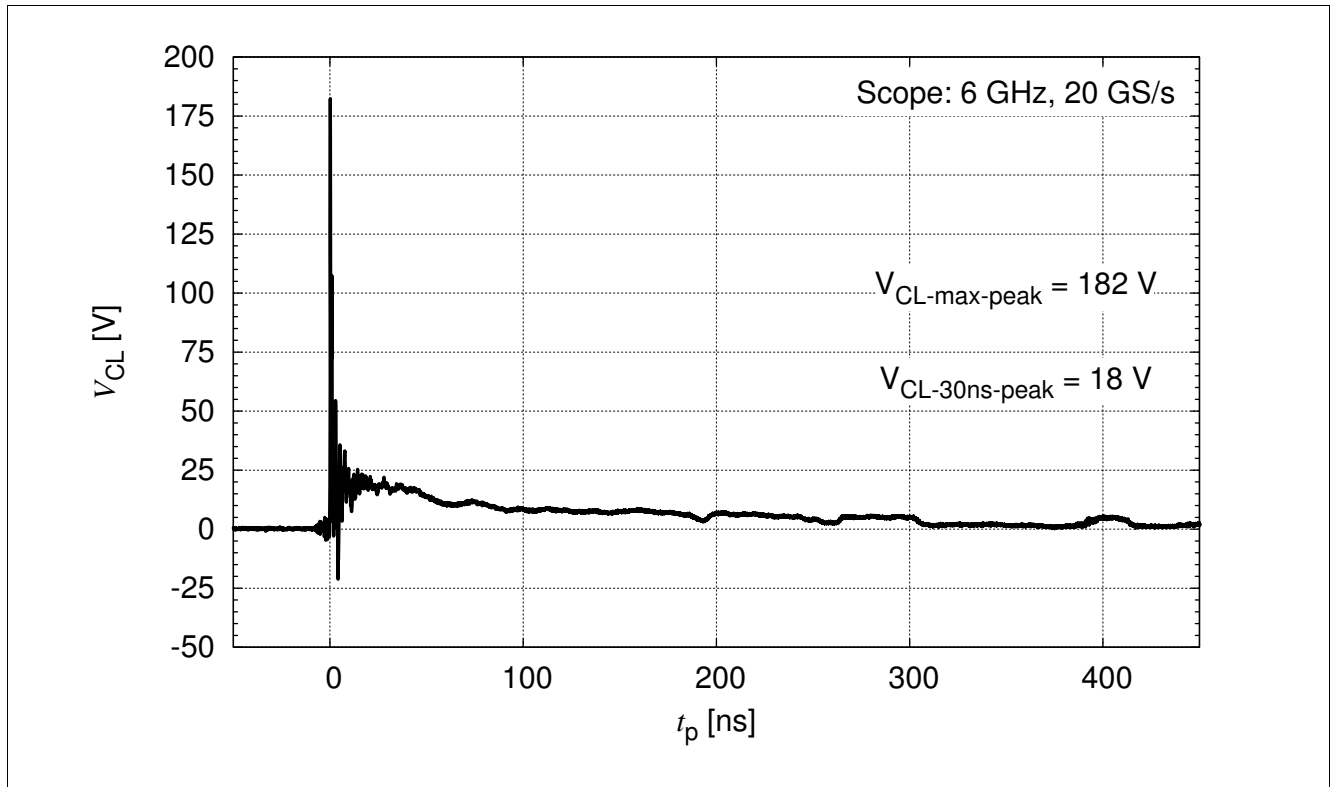


Figure 3-7 Clamping voltage at +15 kV discharge according IEC61000-4-2 ($R = 330 \text{ Ohm}$, $C = 150 \text{ pF}$)

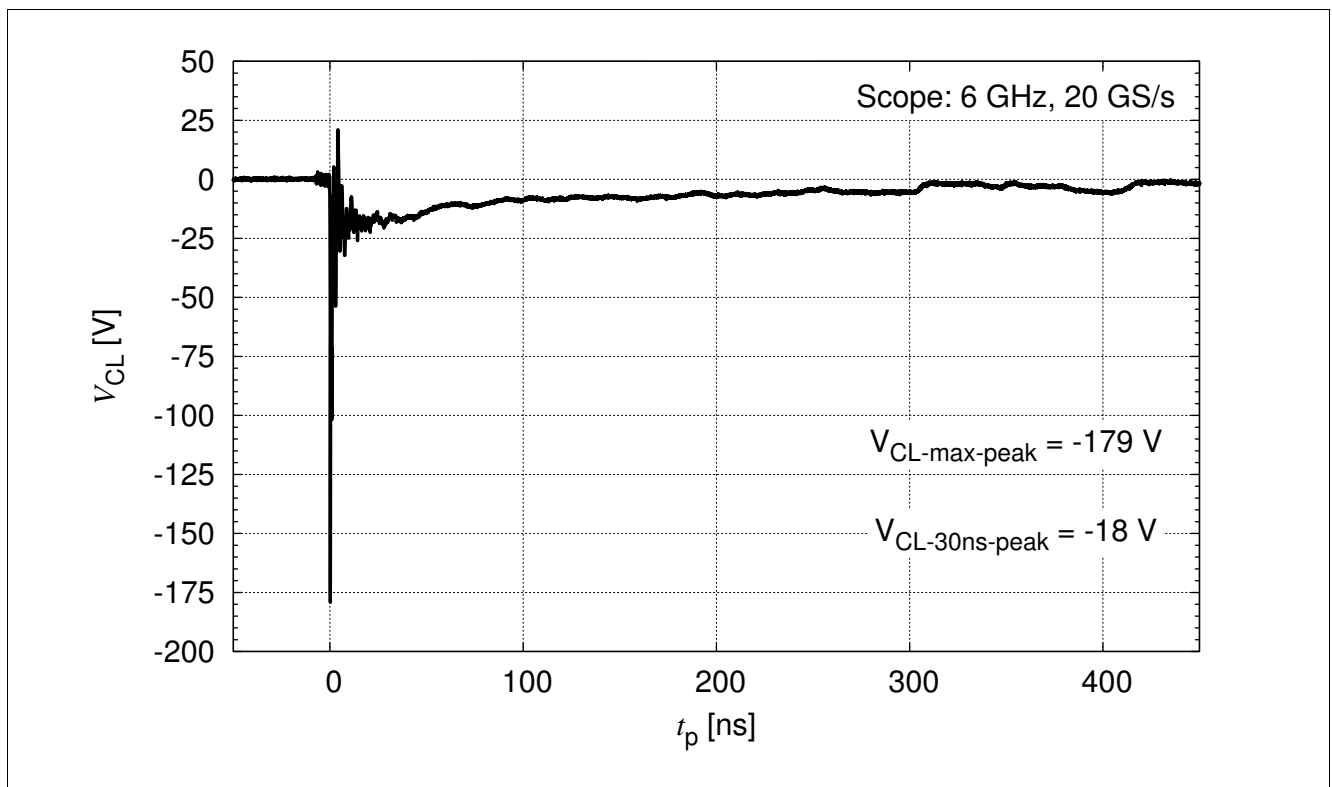


Figure 3-8 Clamping voltage at -15 kV discharge according IEC61000-4-2 ($R = 330 \text{ Ohm}$, $C = 150 \text{ pF}$)

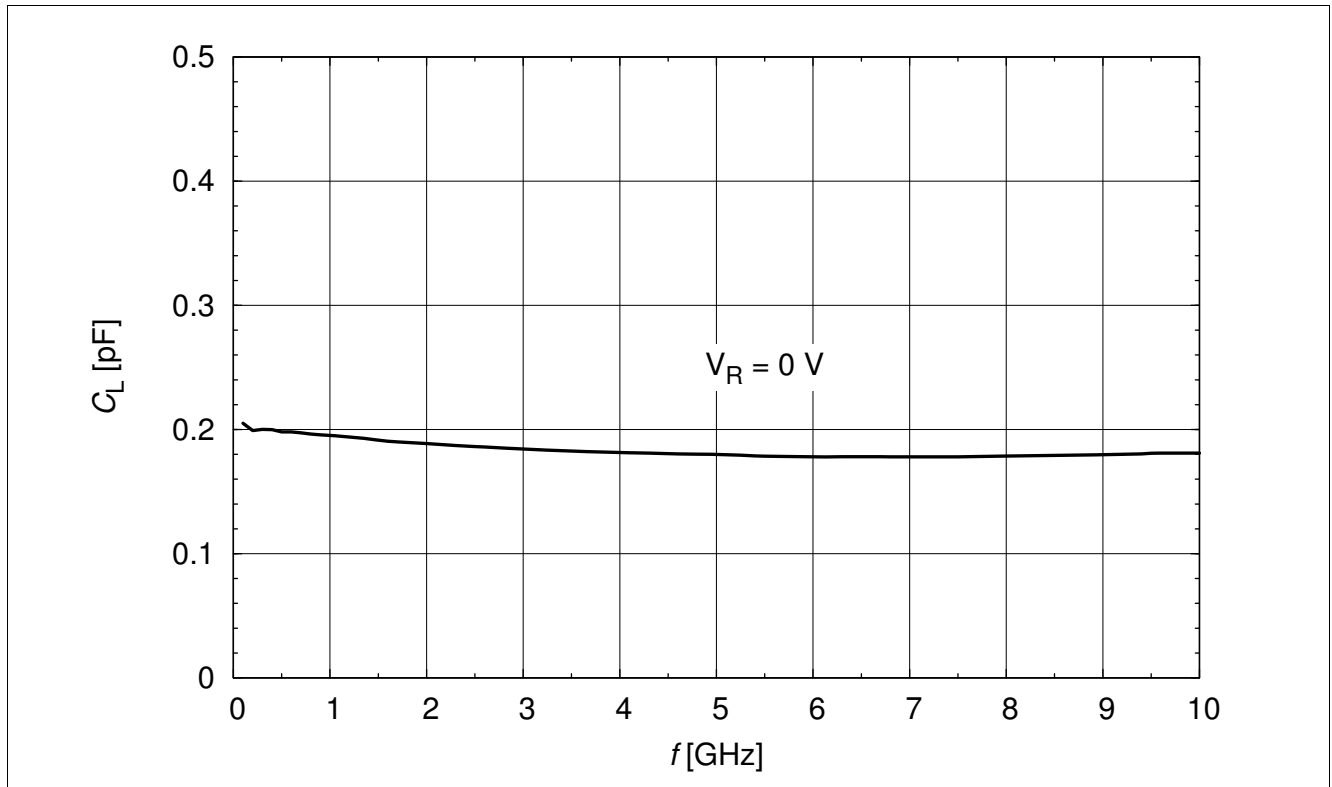


Figure 3-9 Line capacitance: $C_L = f(f)$, $V_R = 0$ V

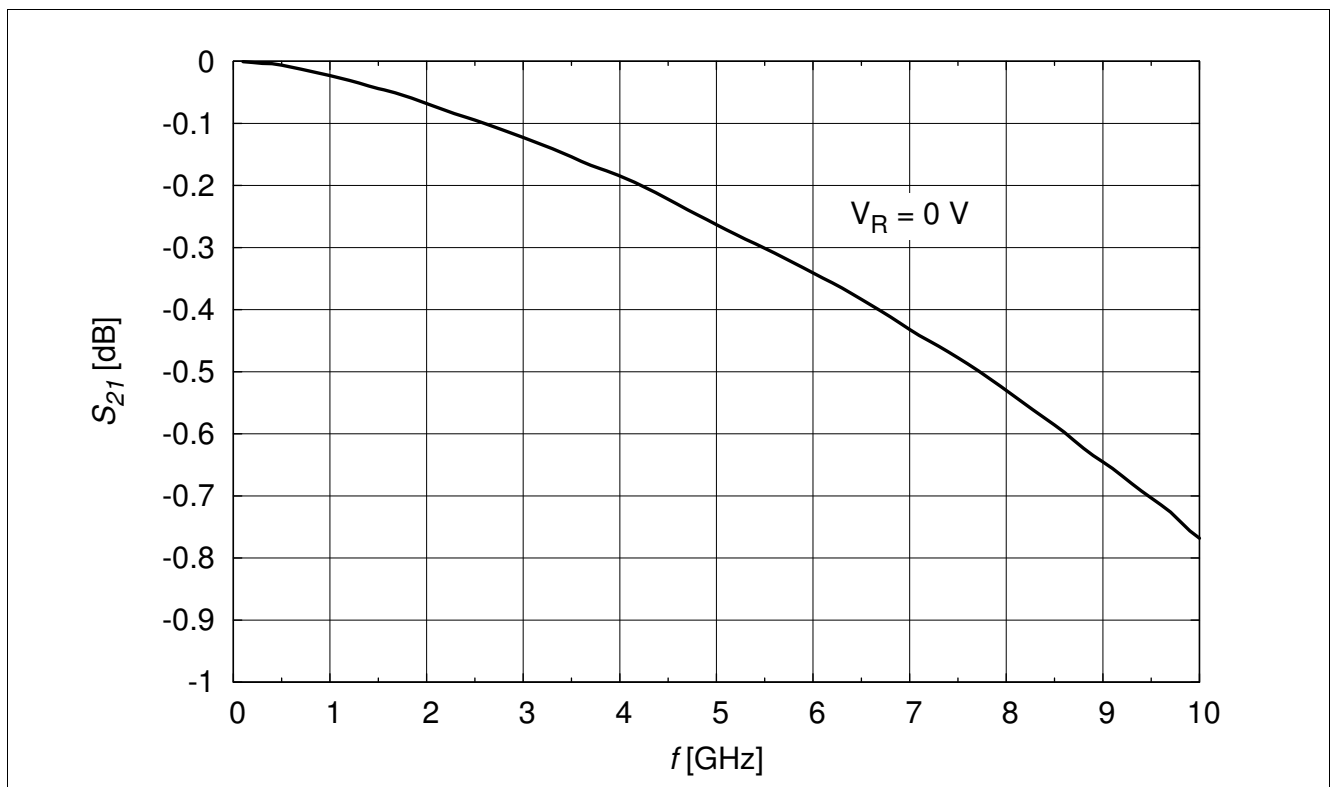


Figure 3-10 Insertion loss: $S_{21} = f(f)$, $V_R = 0$ V

4 Package Information

4.1 PG-TSSLP-2-4[2]

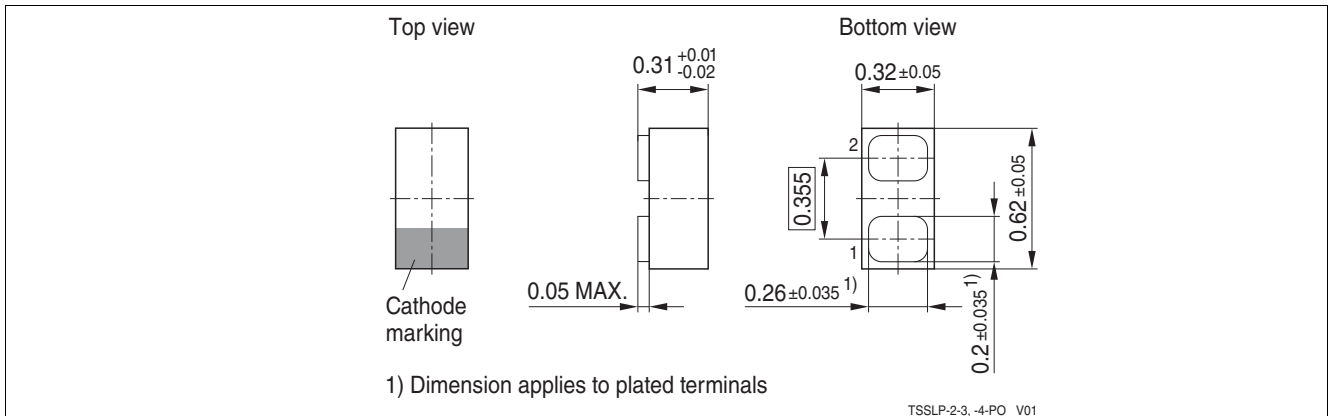


Figure 4-1 PG-TSSLP-2-4 Package outline (dimension in mm)

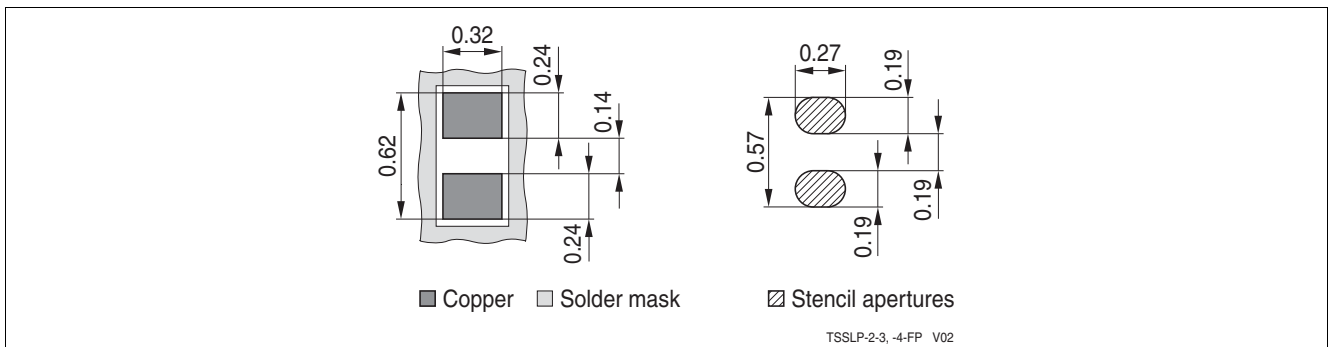


Figure 4-2 PG-TSSLP-2-4 Footprint (dimension in mm)

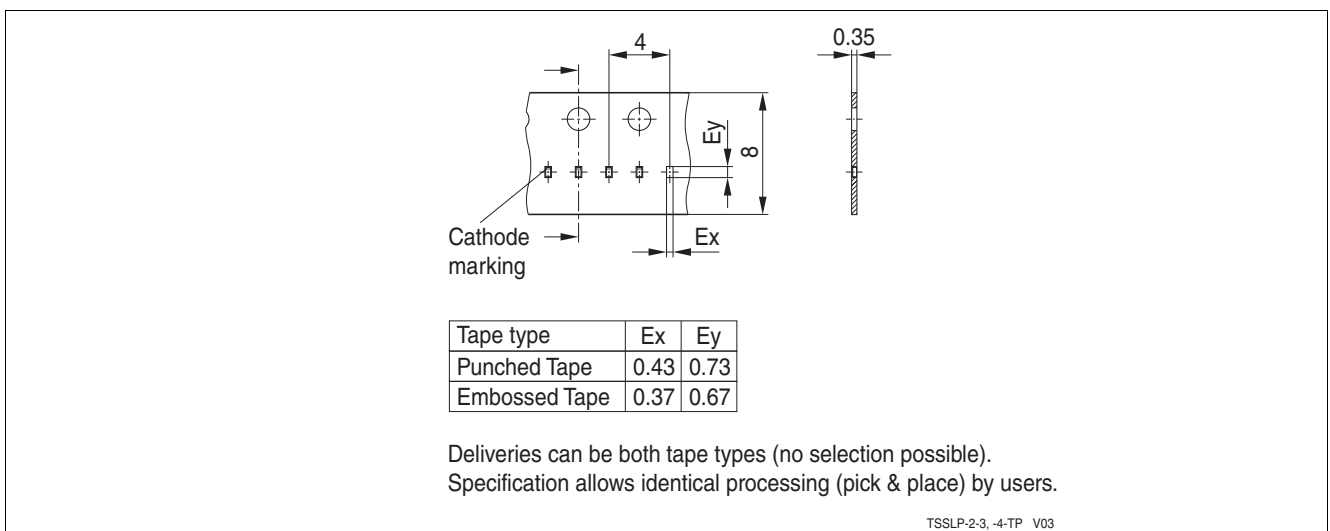


Figure 4-3 PG-TSSLP-2-4 Packing (dimension in mm)

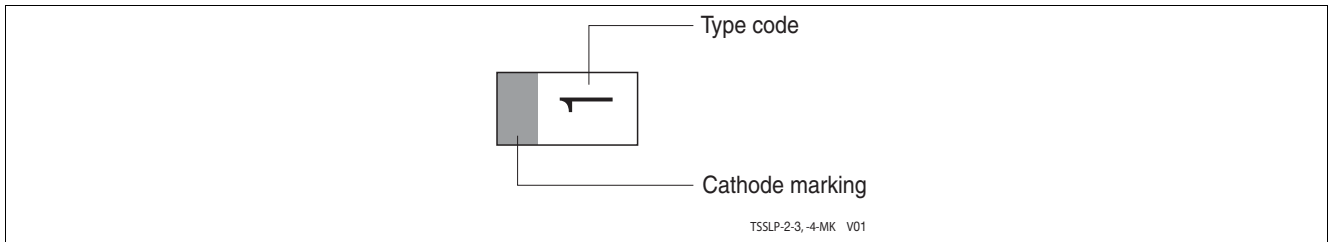


Figure 4-4 PG-TSSLP-2-4 Marking (example)

References

- [1] Infineon AG - **Application Note AN210**: Effective ESD Protection Design at System Level Using VF-TLP Characterization Methodology
- [2] Infineon AG - Recommendations for PCB Assembly of Infineon TSLP and TSSLP Package

www.infineon.com

AMEYA360

Components Supply Platform

Authorized Distribution Brand :



Website :

Welcome to visit www.ameya360.com

Contact Us :

➤ Address :

401 Building No.5, JiuGe Business Center, Lane 2301, Yishan Rd
Minhang District, Shanghai , China

➤ Sales :

Direct +86 (21) 6401-6692

Email amall@ameya360.com

QQ 800077892

Skype ameyasales1 ameyasales2

➤ Customer Service :

Email service@ameya360.com

➤ Partnership :

Tel +86 (21) 64016692-8333

Email mkt@ameya360.com